# NSN 5961-01-168-6505

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-168-6505

# Inclosure Material:

Metal and ceramic

# **Overall Length:**

1.563 inches

# **Overall Height:**

0.350 inches

# **Overall Width:**

1.050 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

#### Field effect

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204aa

#### **Mounting Method:**

# Unthreaded hole

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 4.0 gate to source threshold voltage

## **Current Rating Per Characteristic:**

8.00 amperes zero-gate-voltage drain current

## Power Rating Per Characteristic:

40.0 watts total device dissipation

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

```
---
```

# Demilitarization:

No

## Fiig:

A110a0